## NSN 5961-01-169-4677

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Inclosure Material:
Plastic
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 collector-to-emitter, substaining voltage, base open-circuited and 5.0 emitter to base voltage, instantaneous and 5.0 base to
emitter voltage, instantaneous and 60.0 collector to emitter voltage/static/base open and 100.0 collector-to-emitter voltage, instantaneous
Current Rating Per Characteristic:
4.00 amperes base current, dc nanoamperes
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Fiig:

A110a0

Yes - demil/mli